

Is Now Part of



# **ON Semiconductor**®

# To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (\_), the underscore (\_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (\_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at <a href="mailto:www.onsemi.com">www.onsemi.com</a>. Please email any questions regarding the system integration to <a href="mailto:Fairchild\_questions@onsemi.com">Fairchild\_questions@onsemi.com</a>.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or unavteries, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out or i, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor and is officers, employees, uniotificated use, even if such claim any manner.



## **FQPF22P10 P-Channel QFET<sup>®</sup> MOSFET** -100 V, -13.2 A, 125 mΩ

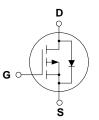
## Description

This P-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor<sup>®</sup>'s proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

## Features

- 13.2 A, -100 V,  $R_{DS(on)}$ =125 m $\Omega(Max.)$  @V<sub>GS</sub>=-10 V, I<sub>D</sub>=-6.6 A
- Low Gate Charge (Typ. 40 nC)
- Low Crss (Typ. 160 pF)
- 100% Avalanche Tested
- 175°C Maximum Junction Temperature Rating





## Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted

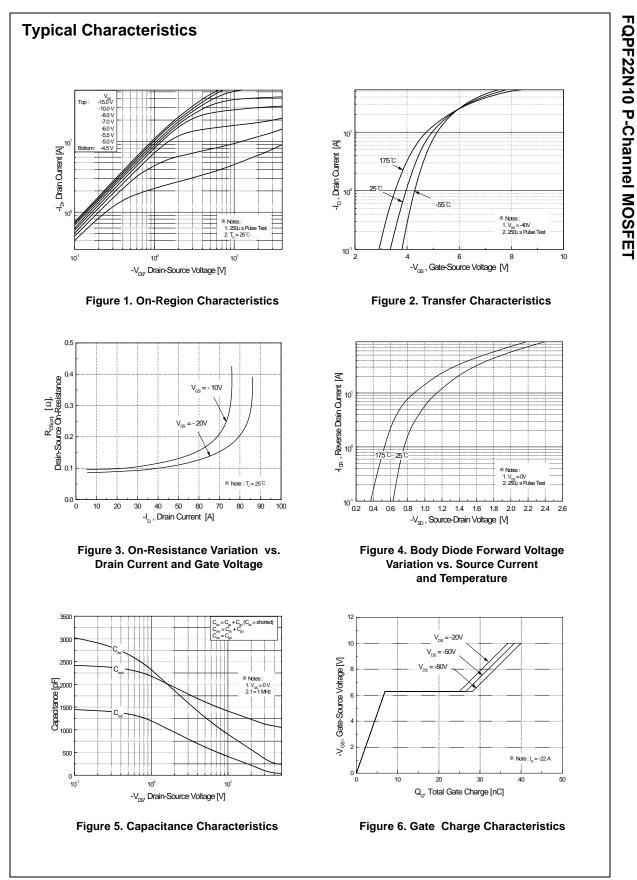
Symbol	Parameter		FQPF22P10	Unit	
V <sub>DSS</sub>	Drain-Source Voltage		-100	V	
I <sub>D</sub>	Drain Current - Continuous ( $T_C = 25^\circ$	C)	-13.2	A	
	- Continuous (T <sub>C</sub> = 100	°C)	-9.3	A	
I <sub>DM</sub>	Drain Current - Pulsed	(Note 1)	-52.8	A	
V <sub>GSS</sub>	Gate-Source Voltage		± 30	V	
E <sub>AS</sub>	Single Pulsed Avalanche Energy	(Note 2)	710	mJ	
AR	Avalanche Current	(Note 1)	-13.2	А	
E <sub>AR</sub>	Repetitive Avalanche Energy	(Note 1)	4.5	mJ	
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	-6.0	V/ns	
PD	Power Dissipation ( $T_C = 25^{\circ}C$ )		45	W	
	- Derate above 25°C		0.3	W/°C	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range		-55 to +175	°C	
ΓL	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds		300	°C	

## **Thermal Characteristics**

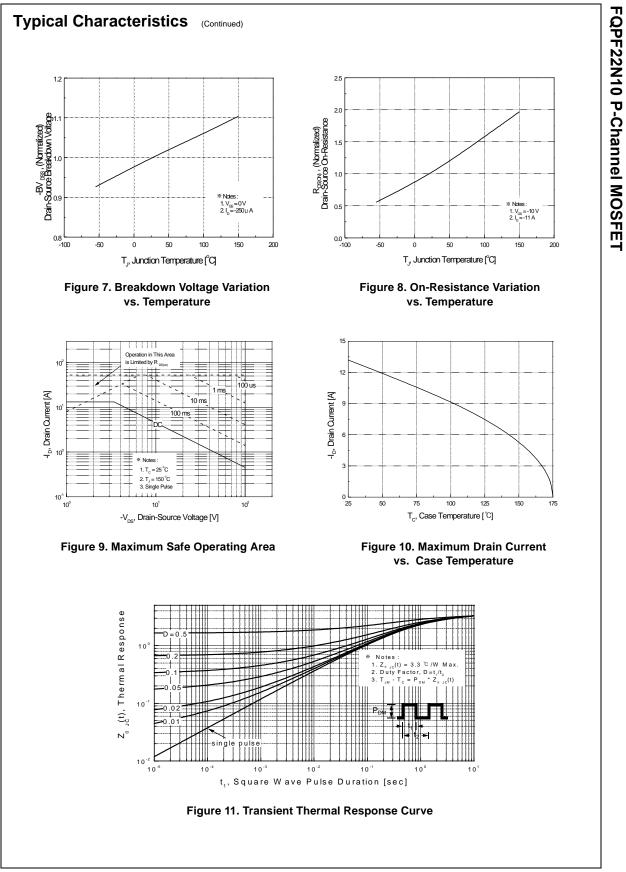
Symbol	Parameter	Тур	Max	Unit
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction-to-Case		3.3	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction-to-Ambient		62.5	°C/W

March 2013

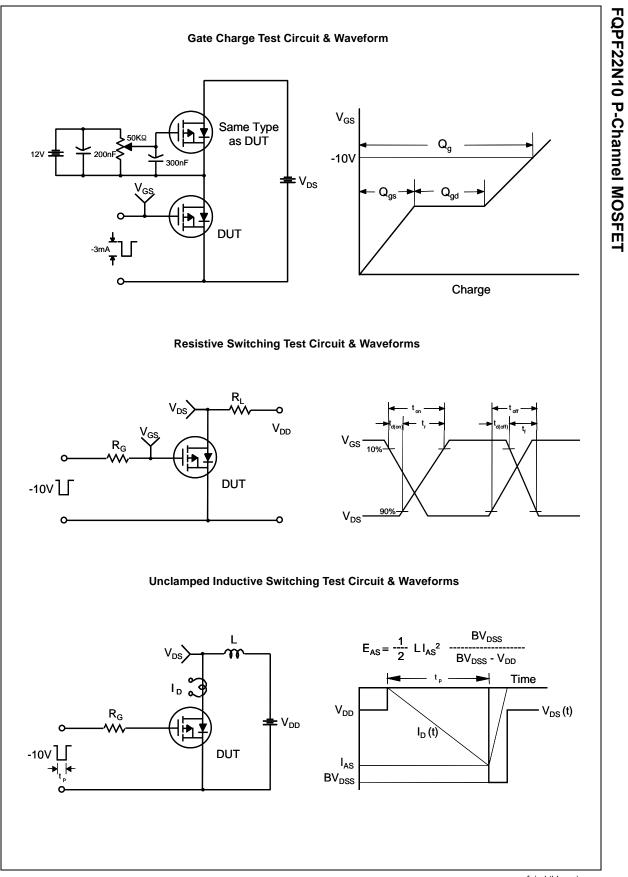
Symbol	Parameter	Test Conditions		Min	Тур	Max	Unit
Off Cha	racteristics						
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0 V, I <sub>D</sub> = -250 μA		-100			V
ΔBV <sub>DSS</sub> ′ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient	$I_D = -250 \mu$ A, Referenced to 25°C			-0.1		V/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = -100 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$				-1	μA
	-	V <sub>DS</sub> = -80 V, T <sub>C</sub> = 125°C				-10	μΑ
GSSF	Gate-Body Leakage Current, Forward	$V_{GS}$ = -30 V, $V_{DS}$ = 0 V				-100	nA
GSSR	Gate-Body Leakage Current, Reverse	$V_{GS} = 30 \text{ V}, V_{DS} = 0 \text{ V}$				100	nA
On Cha	racteristics						
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$		-2.0		-4.0	V
R <sub>DS(on)</sub>	Static Drain-Source On-Resistance	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -6.6 \text{ A}$			0.096	0.125	Ω
ĴFS	Forward Transconductance	V <sub>DS</sub> = -40 V, I <sub>D</sub> = -6.6 A	(Note 4)		11		S
Dynam C <sub>iss</sub>	ic Characteristics				1170	1500	pF
C <sub>oss</sub>	Output Capacitance	V <sub>DS</sub> = -25 V, V <sub>GS</sub> = 0 V, f = 1.0 MHz			460	600	pF
C <sub>rss</sub>	Reverse Transfer Capacitance				160	200	pF
d(on) r	ng Characteristics Turn-On Delay Time Turn-On Rise Time	$V_{DD} = -50 \text{ V}, \text{ I}_{D} = -22 \text{ A},$		17 170	45 350	ns ns	
		V <sub>DD</sub> = -50 V, I <sub>D</sub> = -22 A,					
d(off)	Turn-Off Delay Time	R <sub>G</sub> = 25 Ω (Note 4, 5)		60	130	ns	
f	Turn-Off Fall Time		Note 4, 5)		110	230	ns
ე <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> = -80 V, I <sub>D</sub> = -22 A,			40	50	nC
ຊ <sub>gs</sub>	Gate-Source Charge	$V_{GS} = -10 V$			7.0		nC
ຊ <sub>gd</sub>	Gate-Drain Charge	(Note 4, 5)			21		nC
	euros Diado Characteristico e	d Movimum Dotingo					
s s	ource Diode Characteristics an Maximum Continuous Drain-Source Dio					-13.2	Α
SM	Maximum Pulsed Drain-Source Diode F					-52.8	A
V <sub>SD</sub>	Drain-Source Diode Forward Voltage					-4.0	V
rr	Reverse Recovery Time	$V_{GS} = 0 V, I_S = -22 A,$			110		ns
2 <sub>rr</sub>	Reverse Recovery Charge	dl <sub>F</sub> / dt = 100 A/µs	(Note 4)		0.6		μC
L = 6.1mH, I I <sub>SD</sub> ≤ -22A,	ating : Pulse width limited by maximum junction tempe $_{AS}$ = -13.2A, V <sub>DD</sub> = -25V, R <sub>G</sub> = 25 Ω, Starting T <sub>J</sub> = 25° di/dt $\leq 300A/\mu$ s, V <sub>DD</sub> $\leq BV_{DSS}$ , Starting T <sub>J</sub> = 25°C Pulse width $\leq 300$ µs, Duty cycle $\leq 2\%$						
	ndependent of operating temperature						



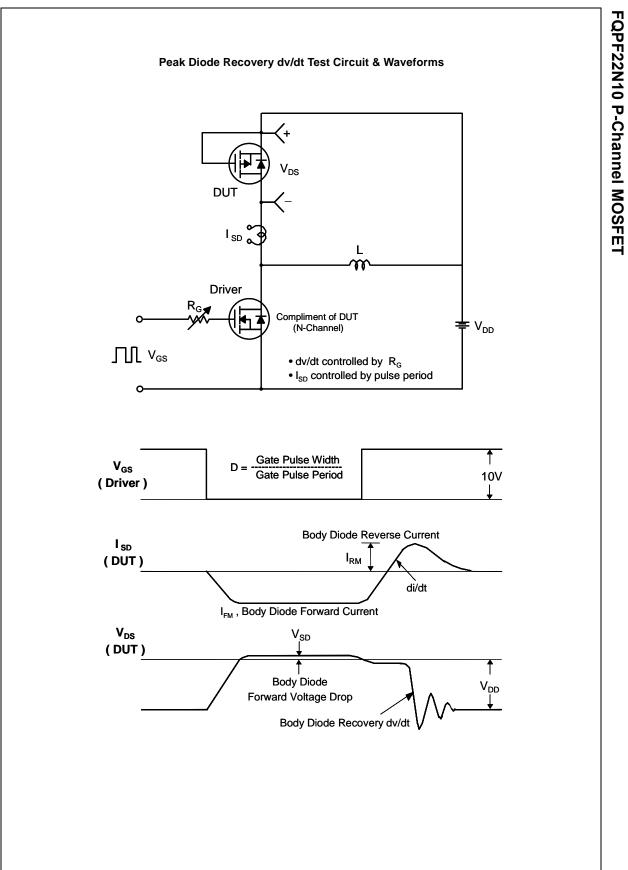
©2002 Fairchild Semiconductor Corporation FQPF22P10 Rev. C0



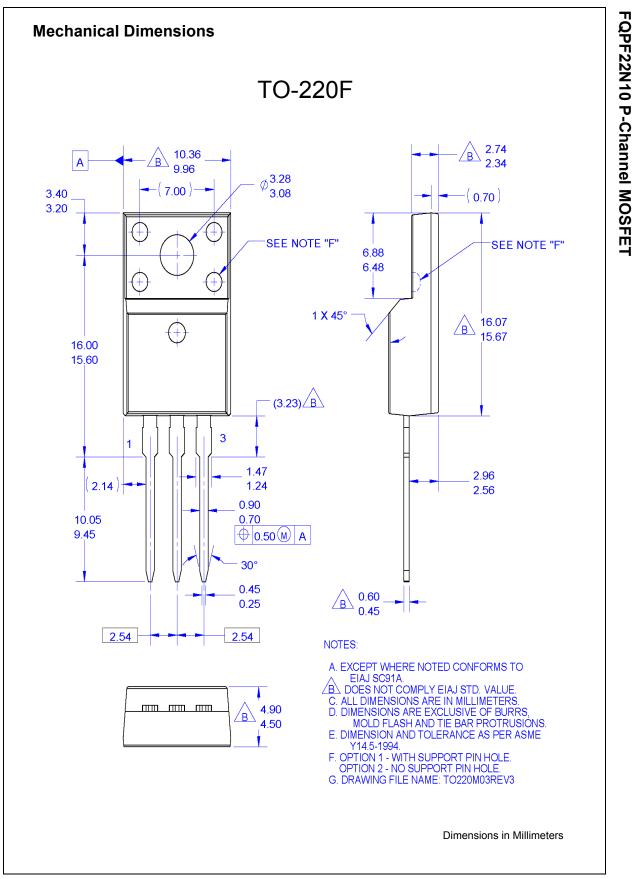
www.fairchildsemi.com



©2002 Fairchild Semiconductor Corporation FQPF22P10 Rev. C0



FQPF22P10 Rev. C0



www.fairchildsemi.com



SEMICONDUCTOR

#### TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

R

2Cool™ AccuPower™ AX-CAP® BitSiC™ Build it Now™ CorePLUS™ CorePOWER™ CROSSVOLT™ CTI ™ Current Transfer Logic™ DEUXPEED<sup>®</sup> Dual Cool™ **EcoSPARK<sup>®</sup>** EfficentMax™ **ESBC™** 

F Fairchild® Fairchild Semiconductor® FACT Quiet Series™ FACT<sup>®</sup> FAST® FastvCore™ FETBench™

FPS™ F-PFS™ FRFET® Global Power Resource<sup>SM</sup> Green Bridge™ Green FPS™ Green FPS™ e-Series™ Gmax™ GTO™ IntelliMAX™ **ISOPLANAR™** Marking Small Speakers Sound Louder and Better™ MegaBuck™ MIČROCOUPLER™ MicroFET™ MicroPak™ MicroPak2™ MillerDrive™ MotionMax™ mWSaver™ OptoHiT™ **OPTOLOGIC**® **OPTOPLANAR<sup>®</sup>** 

PowerTrench<sup>®</sup> PowerXS™ Programmable Active Droop™ OFFT QS™ Quiet Series™ RapidConfigure™ тм ng our world, 1mW/W/kW at a time™ SignalWise™ SmartMax™ SMART START™ Solutions for Your Success™ SPM® STEALTH™ SuperFET<sup>®</sup> SuperSOT™-3 SuperSOT™-6 SuperSOT™-8 SupreMOS® SvncFET™

SYSTEM<sup>®\*</sup> GENERAL TinyBoost™ TinyBuck™ TinyCalc™ TinyLogic® TINYOPTO™ TinyPower™ TinyPWM™ TinyWire™ TranSiC® TriFault Detect™ TRUECURRENT®\* μSerDes™ UHC® Ultra FRFET™ UniFET™ VCX™ VisualMax™ VoltagePlus™ XS™

Svnc-Lock™

\*Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

#### DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

#### As used here in:

- Life support devices or systems are devices or systems which, (a) are 1. intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or 2. system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

#### ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.Fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

#### **PRODUCT STATUS DEFINITIONS Definition of Terms**

	Definition
Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.
	First Production

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor has against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death ass

### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for MOSFET category:

Click to view products by ON Semiconductor manufacturer:

Other Similar products are found below :

614233C 648584F IRFD120 JANTX2N5237 FCA20N60\_F109 FDZ595PZ 2SK2545(Q,T) 405094E 423220D TPCC8103,L1Q(CM MIC4420CM-TR VN1206L SBVS138LT1G 614234A 715780A NTNS3166NZT5G SSM6J414TU,LF(T 751625C BUK954R8-60E NTE6400 SQJ402EP-T1-GE3 2SK2614(TE16L1,Q) 2N7002KW-FAI DMN1017UCP3-7 EFC2J004NUZTDG ECH8691-TL-W FCAB21350L1 P85W28HP2F-7071 DMN1053UCP4-7 NTE221 NTE222 NTE2384 NTE2903 NTE2941 NTE2945 NTE2946 NTE2960 NTE2967 NTE2969 NTE2976 NTE455 NTE6400A NTE2910 NTE2916 NTE2956 NTE2911 DMN2080UCB4-7 TK10A80W,S4X(S SSM6P69NU,LF DMP22D4UF0-7B